



SANYO Semiconductors

DATA SHEET

2SJ655

P-Channel Silicon MOSFET

General-Purpose Switching Device Applications

Features

- Low ON-resistance.
- 4V drive.
- Ultrahigh-speed switching.
- Motor drive, DC / DC converter.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		-100	V
Gate-to-Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	I _D		-12	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	-48	A
Allowable Power Dissipation	P _D		2.0	W
		Tc=25°C	25	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =-1mA, V _{GS} =0	-100			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =-100V, V _{GS} =0			-1	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} = ±16V, V _{DS} =0			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =-10V, I _D =-1mA	-1.2		-2.6	V
Forward Transfer Admittance	y _{fs}	V _{DS} =-10V, I _D =-6A	9	13		S
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D =-6A, V _{GS} =-10V		100	136	mΩ
	R _{DS(on)2}	I _D =-6A, V _{GS} =-4V		136	190	mΩ
Input Capacitance	C _{iss}	V _{DS} =-20V, f=1MHz		2090		pF
Output Capacitance	C _{oss}	V _{DS} =-20V, f=1MHz		155		pF
Reverse Transfer Capacitance	C _{rss}	V _{DS} =-20V, f=1MHz		108		pF

Marking : J655

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SANYO Electric Co.,Ltd. Semiconductor Company

TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

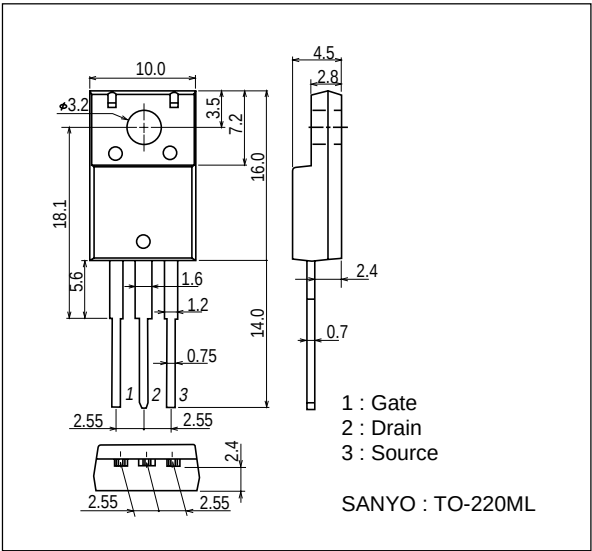
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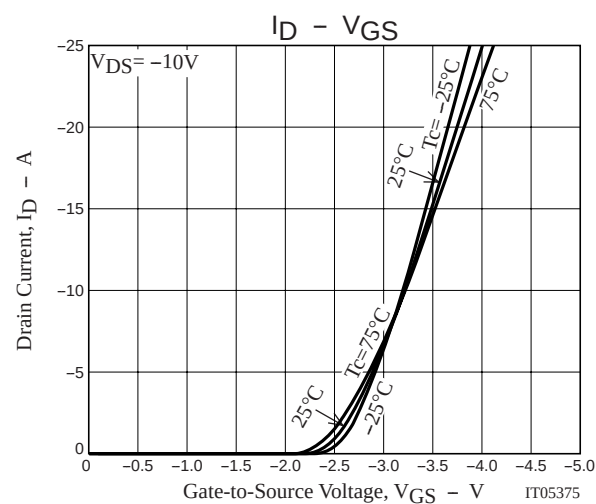
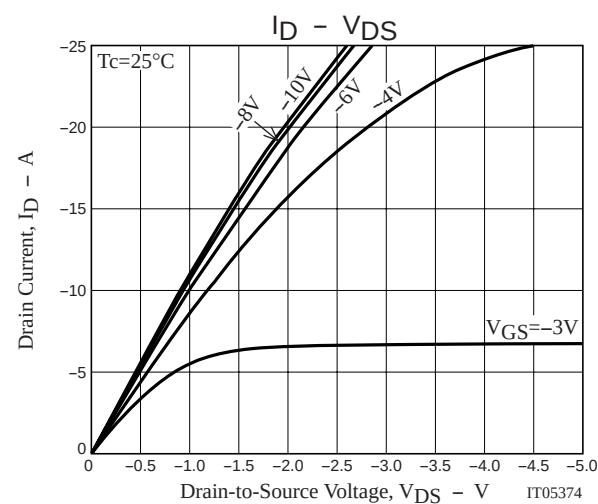
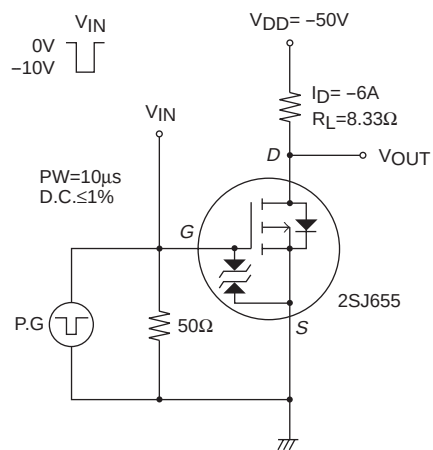
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit.		17		ns
Rise Time	t_r	See specified Test Circuit.		95		ns
Turn-OFF Delay Time	$t_{d(off)}$	See specified Test Circuit.		187		ns
Fall Time	t_f	See specified Test Circuit.		95		ns
Total Gate Charge	Q_g	$V_{DS}=-50V, V_{GS}=-10V, I_D=-12A$		41		nC
Gate-to-Source Charge	Q_{gs}	$V_{DS}=-50V, V_{GS}=-10V, I_D=-12A$		7		nC
Gate-to-Drain "Miller" Charge	Q_{gd}	$V_{DS}=-50V, V_{GS}=-10V, I_D=-12A$		9		nC
Diode Forward Voltage	V_{SD}	$I_S=-12A, V_{GS}=0$		-0.88	-1.2	V

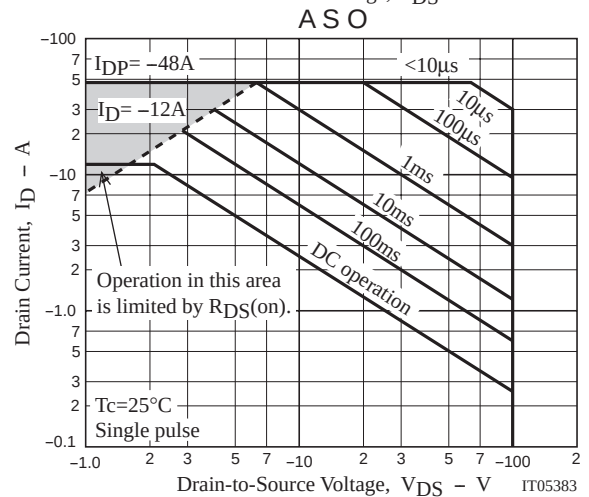
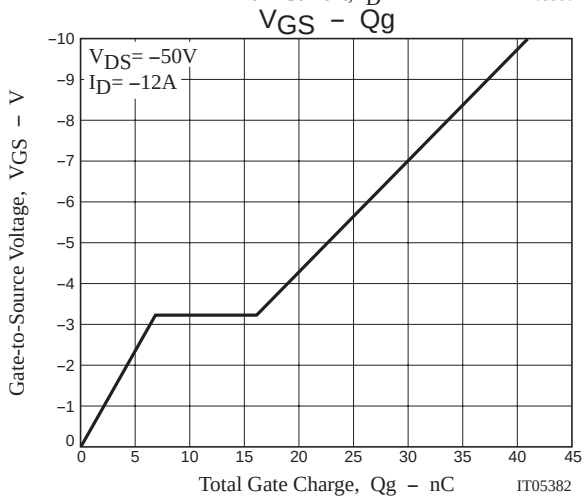
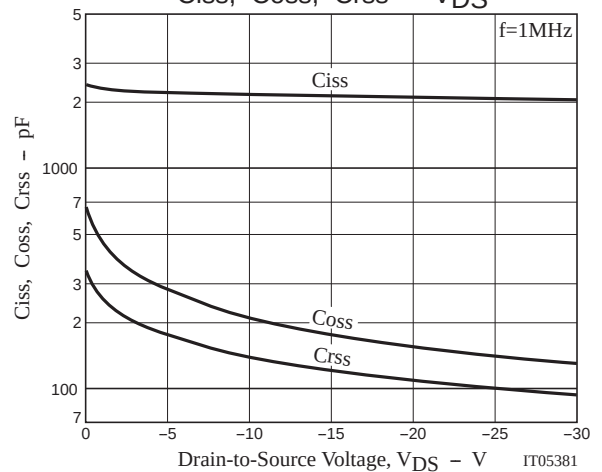
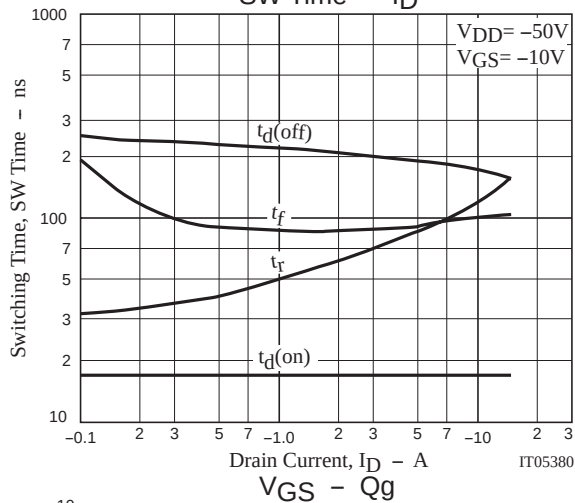
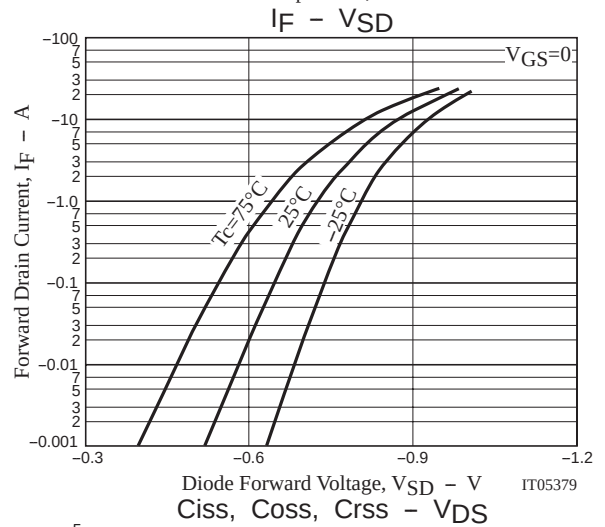
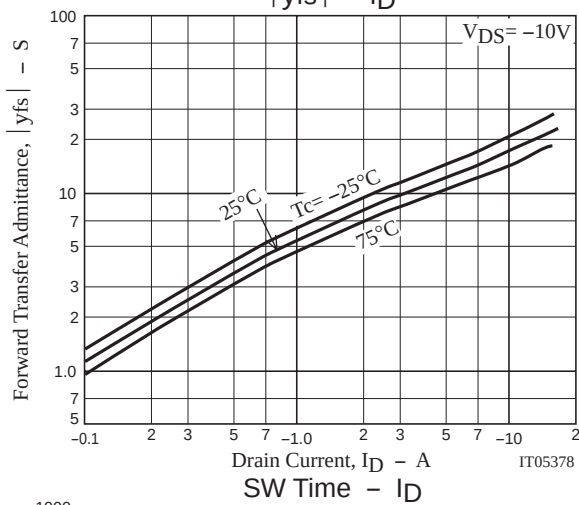
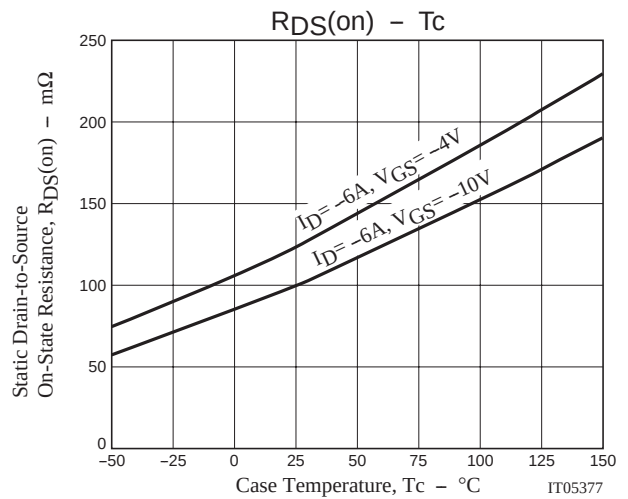
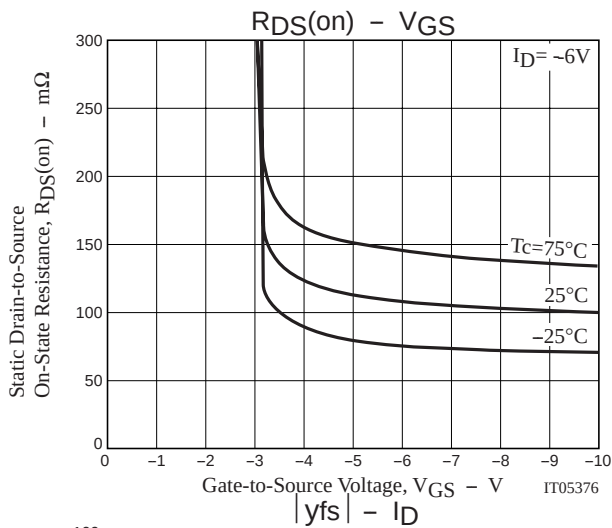
Package Dimensions

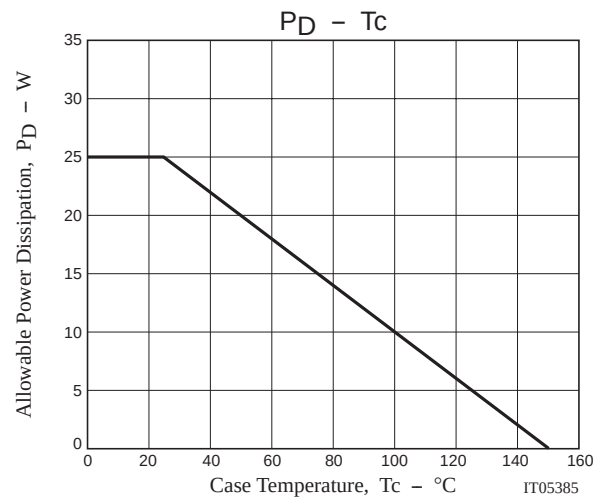
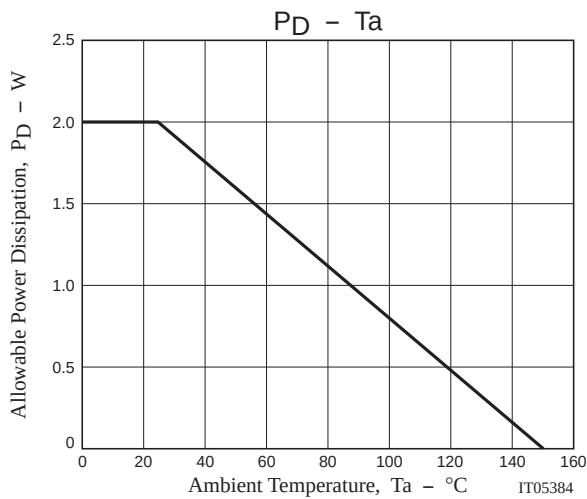
unit : mm
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Switching Time Test Circuit







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